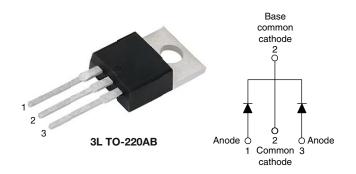
Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 30 A



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PRIMARY CHARACTERISTICS					
I _{F(AV)} 2 x 30 A					
V _R	100 V				
V _F at I _F	0.69 V				
I _{RM} max.	20 mA at 125 °C				
T _J max.	175 °C				
E _{AS}	11.25 mJ				
Package	3L TO-220AB				
Circuit configuration	Common cathode				

FEATURES

- 175 °C T_J operation
- Low forward voltage dropHigh frequency operation



HALOGEN

FREE

- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	SYMBOL CHARACTERISTICS					
I _{F(AV)}	Rectangular waveform (per device)	60	А			
V _{RRM}		100	V			
I _{FRM}	T _C = 139 °C (per leg)	60	٨			
I _{FSM}	t _p = 5 μs sine	1500	A			
V _F	30 A _{pk} , T _J = 125 °C	0.69	V			
TJ	Range	-65 to +175	°C			

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-63CTQ100-M3 UNITS						
Maximum DC reverse voltage	V _R	100	N/			
Maximum working peak reverse voltage	V _{RWM}	100	v			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average forward per leg		50 % duty cycle at T_{C} = 139 °C, rectangular waveform		30			
current per device	I _{F(AV)}			60			
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 140 °C		60	А		
Maximum peak one cycle non-repetitive	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load	1500			
surge current per leg		10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	300			
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 0.75 A, L = 40 mH		11.25	mJ		
Repetitive avalanche current per leg		Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.75	А		

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS	
		30 A	T 05.00	0.78	0.82	V	
Maximum famuard valtare dran	V (1)	60 A	T _J = 25 °C	0.94	1.0		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	30 A	T 105 00	0.64	0.69		
		60 A	T _J = 125 °C	0.78	0.83		
Maximum instantaneous reverse current	I _{RM}	T _J = 25 °C	Rated DC voltage	0.02	0.3	mA	
		T _J = 125 °C	haled DC vollage	11	20	MA	
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		11	00	pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane			.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage	ge	T _J , T _{Stg}		-65 to +175	°C	
Maximum thermal resistance junction to case per leg	, ,	R _{thJC}	DC operation	1.2	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50	0/11	
Approvimate weight				2	g	
Approximate weight	Approximate weight			0.07	oz.	
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf ⋅ cm	
	maximum		Non-Inducated tilleads	12 (10)	(lbf · in)	
Marking device			Case style 3L TO-220AB	63CT	Q100	



VS-63CTQ100-M3

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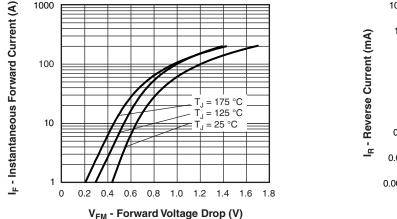


Fig. 1 - Maximum Forward Voltage Drop Characteristics

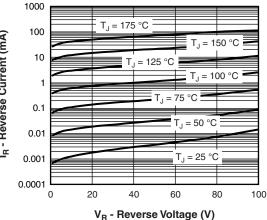


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

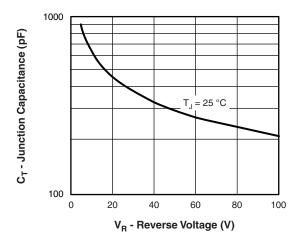
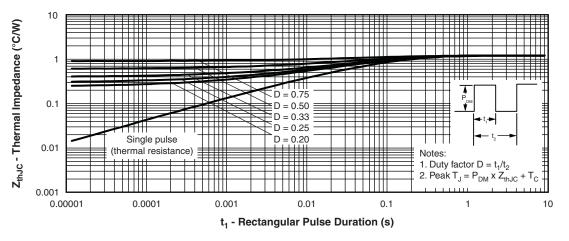
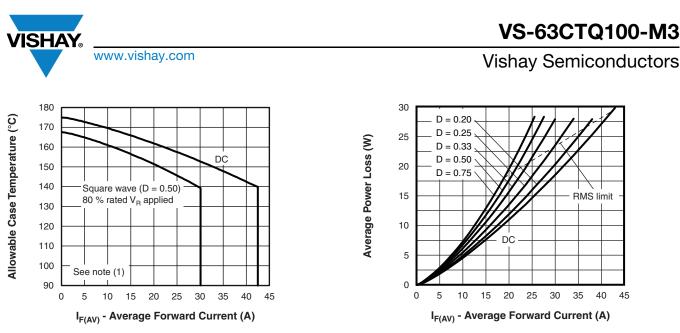


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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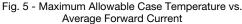


Fig. 6 - Forward Power Loss Characteristics

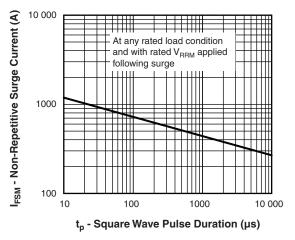


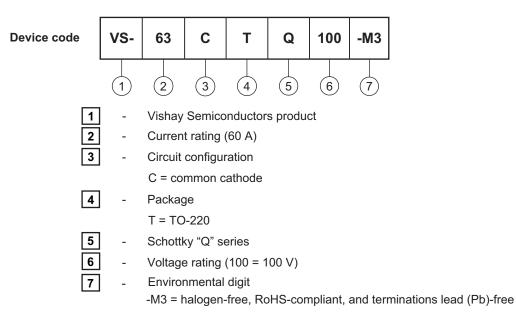
Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note



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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-63CTQ100-M3	50	1000	Antistatic plastic tube				

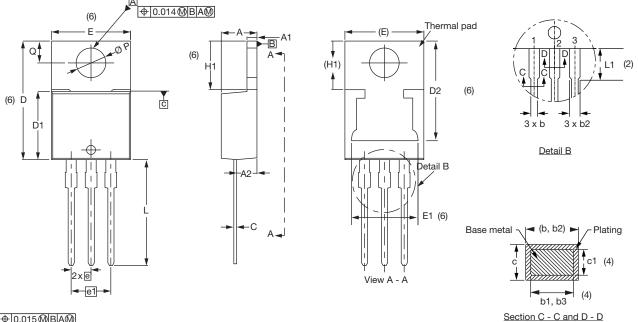
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96154					
Part marking information	www.vishay.com/doc?95028				



Vishay Semiconductors

3L TO-220AB

DIMENSIONS in millimeters and inches



⊕0.015@BA@





SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

_		
Conforms to JEDEC [®]	outline	TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
Е	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

- ⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

Revision: 13-Jun-2019

 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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